



## STGP3NB60F - STGD3NB60F

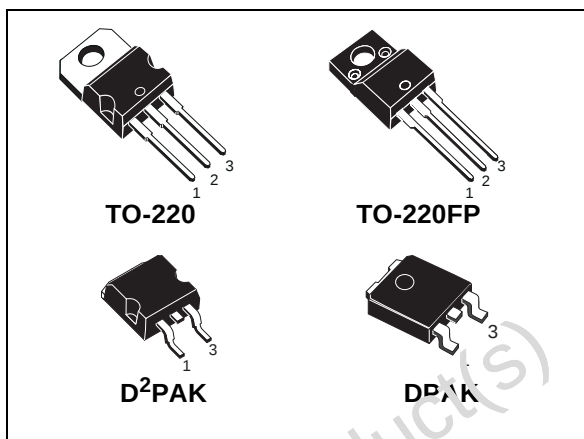
## STGP3NB60FD-STGF3NB60FD-STGB3NB60FD

N-CHANNEL 3A - 600V - TO-220/TO-220FP/DPAK/D<sup>2</sup>PAK

PowerMESH™ IGBT

| TYPE        | V <sub>CES</sub> | V <sub>CE(sat)</sub><br>(Typ) @125°C | I <sub>C</sub><br>@125°C |
|-------------|------------------|--------------------------------------|--------------------------|
| STGP3NB60F  | 600 V            | < 2.4 V                              | 3 A                      |
| STGD3NB60F  | 600 V            | < 2.4 V                              | 3 A                      |
| STGP3NB60FD | 600 V            | < 2.4 V                              | 3 A                      |
| STGF3NB60FD | 600 V            | < 2.4 V                              | 3 A                      |
| STGB3NB60FD | 600 V            | < 2.4 V                              | 3 A                      |

- HIGH INPUT IMPEDANCE (VOLTAGE DRIVEN)
- LOW ON-VOLTAGE DROP (V<sub>cesat</sub>)
- LOW GATE CHARGE
- HIGH CURRENT CAPABILITY
- OFF LOSSES INCLUDE TAIL CURRENT
- HIGH FREQUENCY OPERATION
- SHORT CIRCUIT RATED

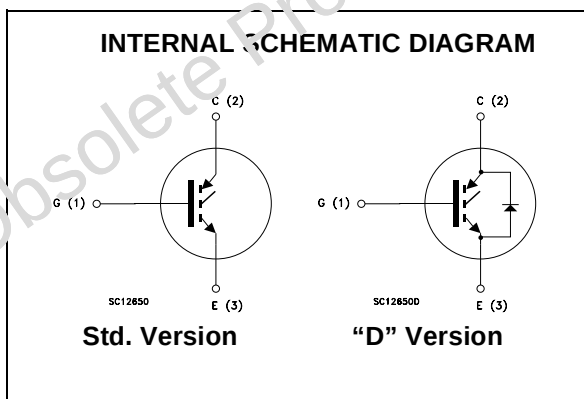


### DESCRIPTION

Using the latest high voltage technology based on a patented strip layout, STMicroelectronics has designed an advanced family of IGBTs, the PowerMESH™ IGBTs, with outstanding performances. The suffix "F" identifies a family optimized to achieve very low switching times for frequency applications (<40 KHz).

### APPLICATIONS

- MOTOR CONTROLS
- SMPS AND PFC IN BOTH HARD SWITCHING AND RESONANT TOPOLOGIES



### ORDERING INFORMATION

| SALES TYPE    | MARKING   | PACKAGE            | PACKAGING   |
|---------------|-----------|--------------------|-------------|
| STGP3NB60F    | GP3NB60F  | TO-220             | TUBE        |
| STGD3NB60FT4  | GD3NB60F  | DPAK               | TAPE & REEL |
| STGP3NB60FD   | GP3NB60FD | TO-220             | TUBE        |
| STGF3NB60FD   | GF3NB60FD | TO-220FP           | TUBE        |
| STGB3NB60FDT4 | GB3NB60FD | D <sup>2</sup> PAK | TAPE & REEL |

**STGP3NB60F/STGD3NB60F/STGP3NB60FD/STGF3NB60FD/STGB3NB60FD****ABSOLUTE MAXIMUM RATINGS**

| Symbol              | Parameter                                                | Value                     |          |      | Unit |
|---------------------|----------------------------------------------------------|---------------------------|----------|------|------|
|                     |                                                          | TO-220/D <sup>2</sup> PAK | TO-220FP | DPAK |      |
| V <sub>CES</sub>    | Collector-Emitter Voltage (V <sub>GS</sub> = 0)          | 600                       |          |      | V    |
| V <sub>ECR</sub>    | Emitter-Collector Voltage                                | 20                        |          |      | V    |
| V <sub>GE</sub>     | Gate-Emitter Voltage                                     | ±20                       |          |      | V    |
| I <sub>C</sub>      | Collector Current (continuous) at T <sub>C</sub> = 25°C  | 6                         |          |      | A    |
| I <sub>C</sub>      | Collector Current (continuous) at T <sub>C</sub> = 100°C | 3                         |          |      | A    |
| I <sub>CM</sub> (■) | Collector Current (pulsed)                               | 24                        |          |      | A    |
| I <sub>f</sub> (1)  | Forward Current                                          | 3                         |          |      | A    |
| I <sub>fm</sub> (1) | Forward Current Pulsed                                   | 24                        |          |      | A    |
| P <sub>TOT</sub>    | Total Dissipation at T <sub>C</sub> = 25°C               | 68                        | 25       | 60   | W    |
|                     | Derating Factor                                          | 0.55                      | 0.2      | 0.47 | W/°C |
| V <sub>ISO</sub>    | Insulation Withstand Voltage A.C.                        | --                        | 2500     | --   | V    |
| T <sub>stg</sub>    | Storage Temperature                                      | – 55 to 150               |          |      | °C   |
| T <sub>j</sub>      | Max. Operating Junction Temperature                      | 150                       |          |      | °C   |

(■) Pulse width limited by safe operating area

(1) For "D" version only

**THERMAL DATA**

|                       |                                         | TO-220/D <sup>2</sup> PAK | TO-220FP | DPAK |      |
|-----------------------|-----------------------------------------|---------------------------|----------|------|------|
| R <sub>thj-case</sub> | Thermal Resistance Junction-case Max    | 1.8                       | 5        | 2.1  | °C/W |
| R <sub>thj-amb</sub>  | Thermal Resistance Junction-ambient Max | 62.5                      |          | 100  | °C/W |
| R <sub>thc-h</sub>    | Thermal Resistance Case-heatsink Typ    | 0.5                       |          |      | °C/W |

**ELECTRICAL CHARACTERISTICS** (T<sub>CASE</sub> = 25°C UNLESS OTHERWISE SPECIFIED)**MAIN PARAMETERS**

| Symbol               | Parameter                                          | Test Conditions                                                                                                      | Min. | Typ.       | Max.      | Unit     |
|----------------------|----------------------------------------------------|----------------------------------------------------------------------------------------------------------------------|------|------------|-----------|----------|
| V <sub>BR(CES)</sub> | Collector-Emitter Breakdown Voltage                | I <sub>C</sub> = 250 μA, V <sub>GE</sub> = 0                                                                         | 600  |            |           | V        |
| I <sub>CES</sub>     | Collector cut-off (V <sub>GE</sub> = 0)            | V <sub>CE</sub> = Max Rating, T <sub>C</sub> = 25°C<br>V <sub>CE</sub> = Max Rating, T <sub>C</sub> = 125°C          |      |            | 50<br>100 | μA<br>μA |
| I <sub>GES</sub>     | Gate-Emitter Leakage Current (V <sub>CE</sub> = 0) | V <sub>GE</sub> = ±20V, V <sub>CE</sub> = 0                                                                          |      |            | ±100      | nA       |
| V <sub>GE(th)</sub>  | Gate Threshold Voltage                             | V <sub>CE</sub> = V <sub>GE</sub> , I <sub>C</sub> = 250 μA                                                          | 3    |            | 5         | V        |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage               | V <sub>GE</sub> = 15 V, I <sub>C</sub> = 3 A<br>V <sub>GE</sub> = 15 V, I <sub>C</sub> = 3 A, T <sub>j</sub> = 125°C |      | 1.9<br>1.6 | 2.4       | V<br>V   |

# STGP3NB60F/STGD3NB60F/STGP3NB60FD/STGF3NB60FD/STGB3NB60FD

## SWITCHING PARAMETERS

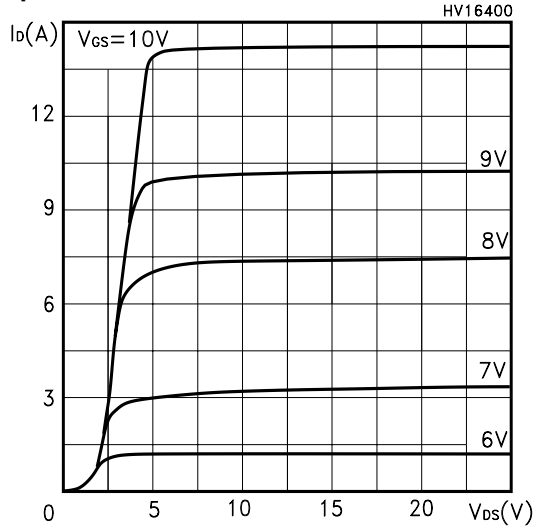
| Symbol                                                                        | Parameter                                                                                                              | Test Conditions                                                                                                                 | Min. | Typ.                                   | Max. | Unit                                                   |
|-------------------------------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------|------|----------------------------------------|------|--------------------------------------------------------|
| $g_{fs}$                                                                      | Forward Transconductance                                                                                               | $V_{CE} = 25 \text{ V}$ , $I_C = 3 \text{ A}$                                                                                   |      | 2                                      |      | S                                                      |
| $C_{ies}$<br>$C_{oes}$<br>$C_{res}$                                           | Input Capacitance<br>Output Capacitance<br>Reverse Transfer Capacitance                                                | $V_{CE} = 25 \text{ V}$ , $f = 1 \text{ MHz}$ , $V_{GE} = 0$                                                                    |      | 230<br>33<br>6                         |      | pF<br>pF<br>pF                                         |
| $Q_g$<br>$Q_{ge}$<br>$Q_{gc}$                                                 | Total Gate Charge<br>Gate-Emitter Charge<br>Gate-Collector Charge                                                      | $V_{CE} = 480 \text{ V}$ , $I_C = 3 \text{ A}$ ,<br>$V_{GE} = 15 \text{ V}$                                                     |      | 16<br>1.5<br>8                         | 20   | nC<br>nC<br>nC                                         |
| $t_{d(on)}$<br>$t_r$                                                          | Turn-on Delay Time<br>Rise Time                                                                                        | $V_{CC} = 480 \text{ V}$ , $I_C = 3 \text{ A}$<br>$R_G = 10 \Omega$ , $V_{GE} = 15 \text{ V}$                                   |      | 12.5<br>4                              |      | ns<br>ns                                               |
| $(di/dt)_{on}$<br>$E_{on}$                                                    | Turn-on Current Slope<br>Turn-on Switching Losses                                                                      | $V_{CC} = 480 \text{ V}$ , $I_C = 3 \text{ A}$ , $R_G = 10 \Omega$<br>$V_{GE} = 15 \text{ V}$ , $T_j = 125^\circ\text{C}$       |      | 840<br>31                              |      | A/ $\mu\text{s}$<br>$\mu\text{J}$                      |
| $t_c$<br>$t_r(V_{off})$<br>$t_{d(off)}$<br>$t_f$<br>$E_{off(**)}$<br>$E_{ts}$ | Cross-over Time<br>Off Voltage Rise Time<br>Delay Time<br>Fall Time<br>Turn-off Switching Loss<br>Total Switching Loss | $V_{CC} = 480 \text{ V}$ , $I_C = 3 \text{ A}$ ,<br>$R_{GE} = 10 \Omega$ , $V_{GE} = 15 \text{ V}$<br>$T_j = 25^\circ\text{C}$  |      | 220<br>60<br>105<br>150<br>125<br>149  |      | ns<br>ns<br>ns<br>ns<br>$\mu\text{J}$<br>$\mu\text{J}$ |
| $t_c$<br>$t_r(V_{off})$<br>$t_{d(off)}$<br>$t_f$<br>$E_{off(**)}$<br>$E_{ts}$ | Cross-over Time<br>Off Voltage Rise Time<br>Delay Time<br>Fall Time<br>Turn-off Switching Loss<br>Total Switching Loss | $V_{CC} = 480 \text{ V}$ , $I_C = 3 \text{ A}$ ,<br>$R_{GE} = 10 \Omega$ , $V_{GE} = 15 \text{ V}$<br>$T_j = 125^\circ\text{C}$ |      | 490<br>174<br>230<br>305<br>295<br>326 |      | ns<br>ns<br>ns<br>ns<br>$\mu\text{J}$<br>$\mu\text{J}$ |

## COLLECTOR-EMITTER DIODE ("D" VERSION)

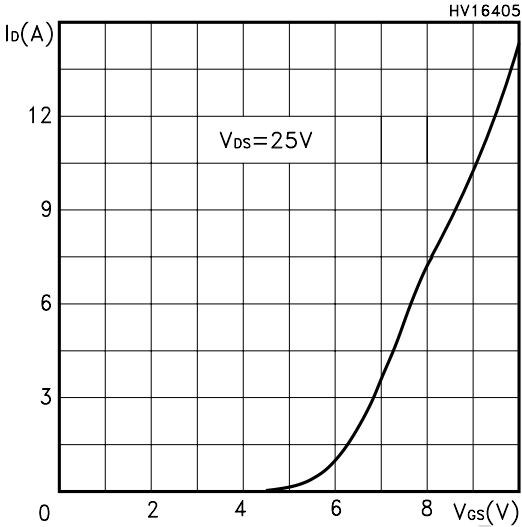
| Symbol                            | Parameter                                                                    | Test Conditions                                                                                                 | Min. | Typ.            | Max. | Unit          |
|-----------------------------------|------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------|------|-----------------|------|---------------|
| $V_f$                             | Forward On-Voltage                                                           | $I_f = 1.5 \text{ A}$<br>$I_f = 1.5 \text{ A}$ , $T_j = 125^\circ\text{C}$                                      |      | 1.31<br>0.95    | 1.8  | V<br>V        |
| $t_{rr}$<br>$Q_{rr}$<br>$I_{rrm}$ | Reverse Recovery Time<br>Reverse Recovery Charge<br>Reverse Recovery Current | $I_f = 3 \text{ A}$ , $V_R = 35 \text{ V}$ ,<br>$T_j = 125^\circ\text{C}$ , $di/dt = 100 \text{ A}/\mu\text{s}$ |      | 45<br>70<br>2.7 |      | ns<br>nC<br>A |

Note: 1. Pulsed: Pulse duration = 300  $\mu\text{s}$ , duty cycle 1.5 %.  
2. Pulse width limited by max. junction temperature.  
(\*\*) Losses include Also the Tail (Jedec Standardization)

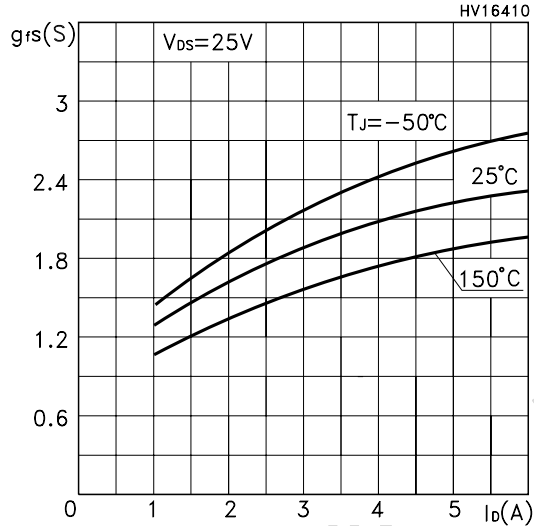
Output Characteristics



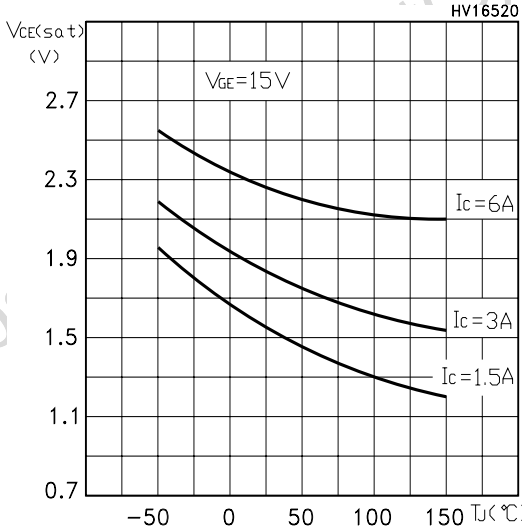
Transfer Characteristics



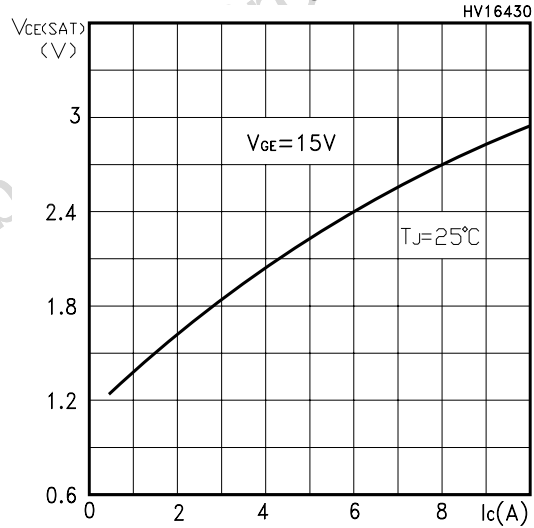
Transconductance



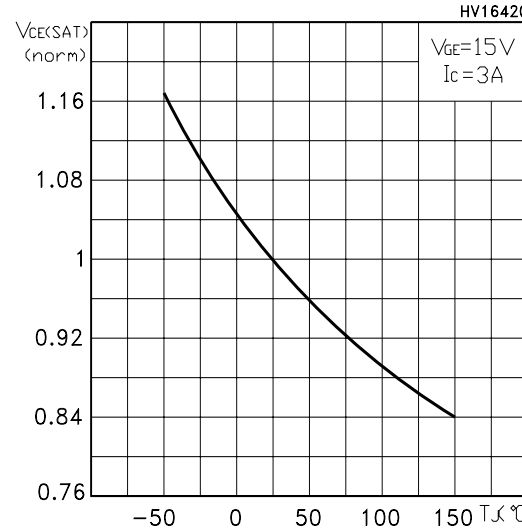
Collector-Emitter On Voltage vs Temperature



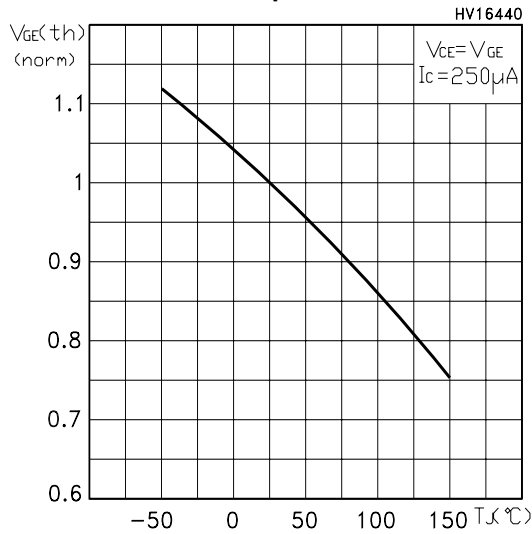
Collector-Emitter On Voltage vs Collector Current



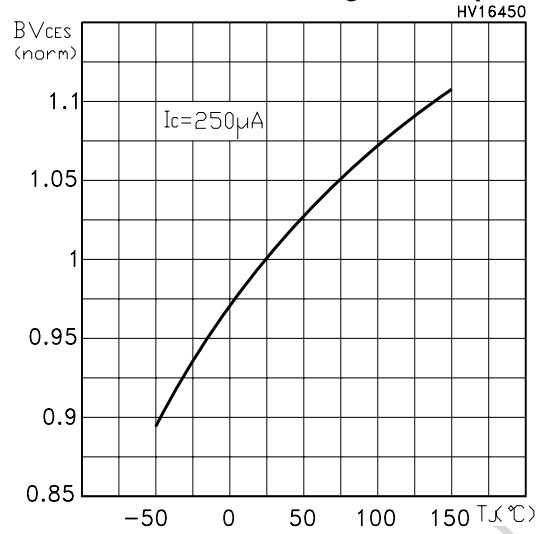
Normalized Collector-Emitter On Voltage vs Temp.



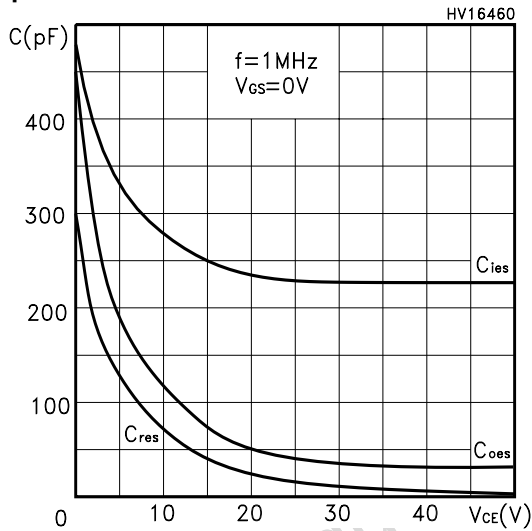
Gate Threshold vs Temperature



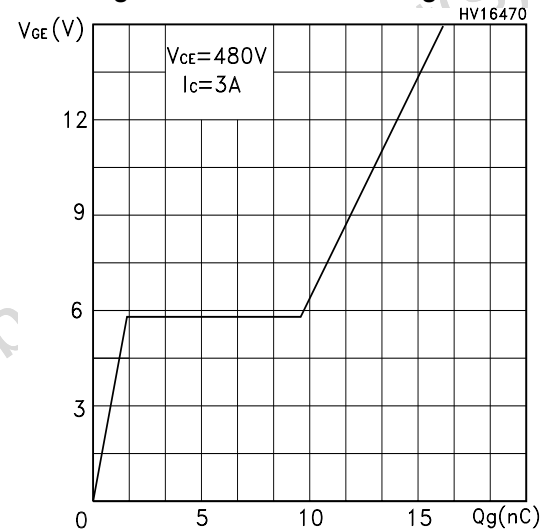
Normalized Breakdown Voltage vs Temperature



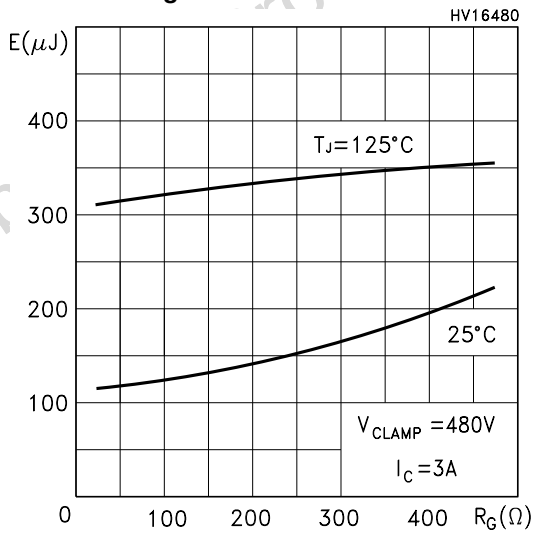
Capacitance Variations



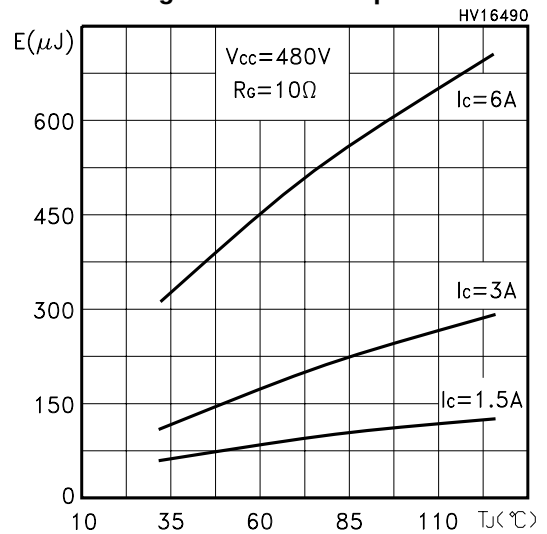
Gate Charge vs Gate-Emitter Voltage



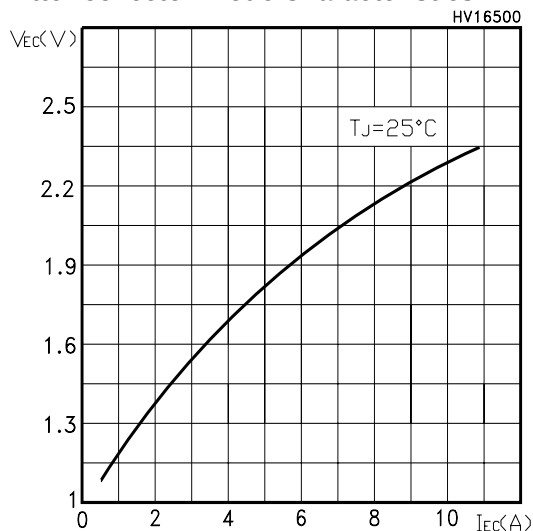
Total Switching Losses vs Gate Resistance



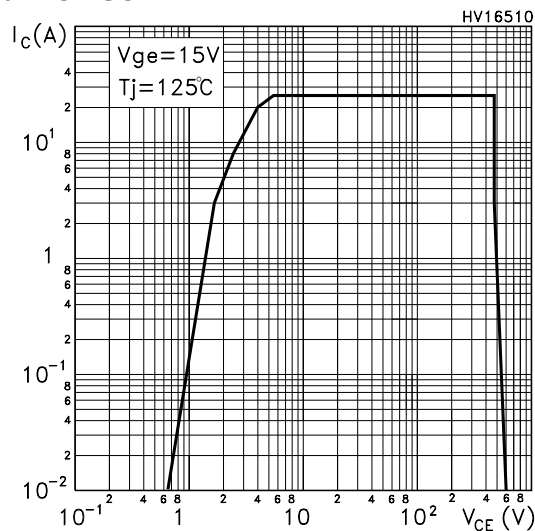
Total Switching Losses vs Temperature



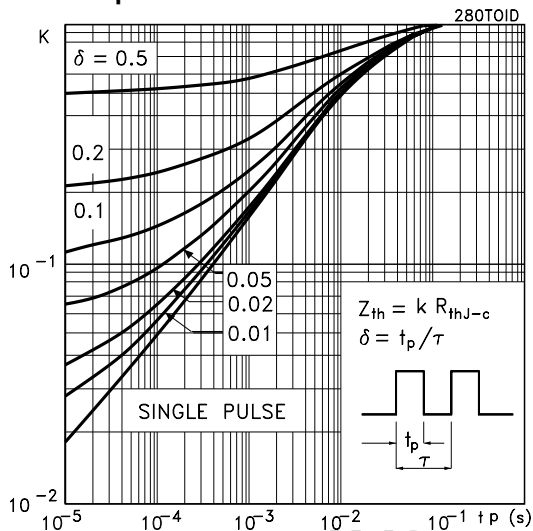
### Emitter-collector Diode Characteristics



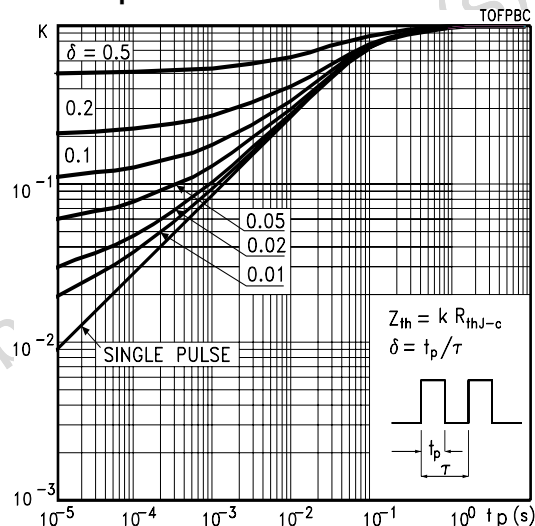
### Turn-Off SOA



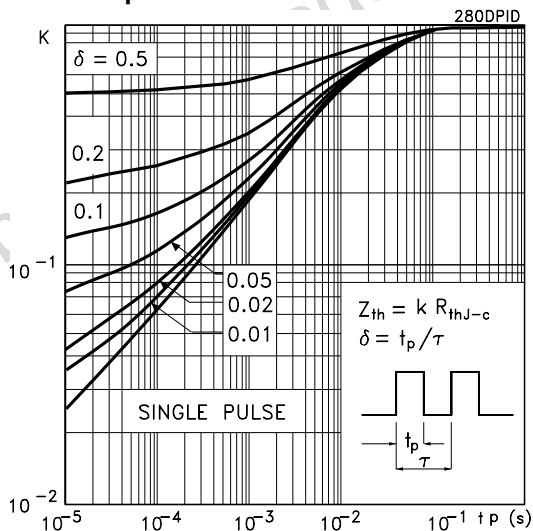
### Thermal Impedance for TO-220 / D2PAK

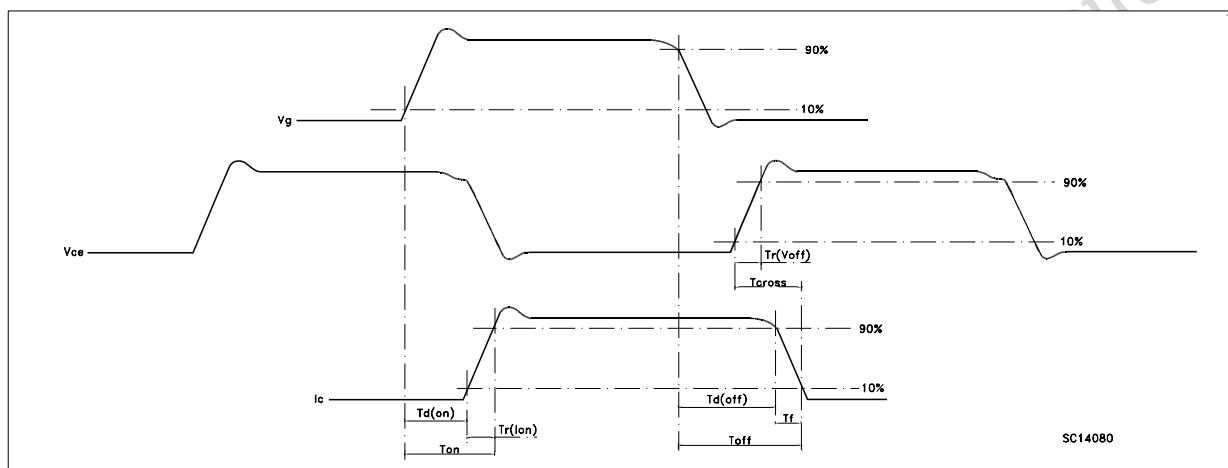
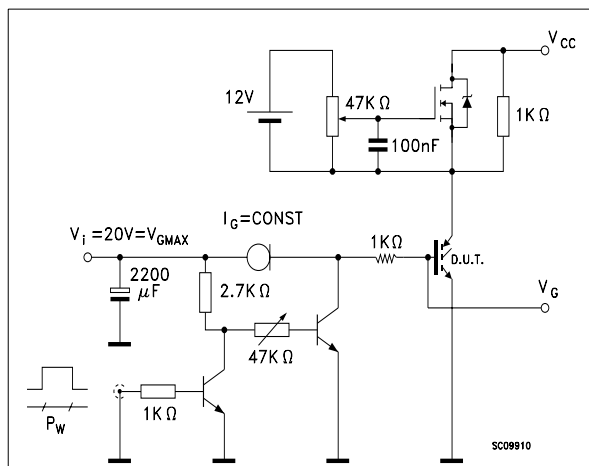


### Thermal Impedance for TO-220FP



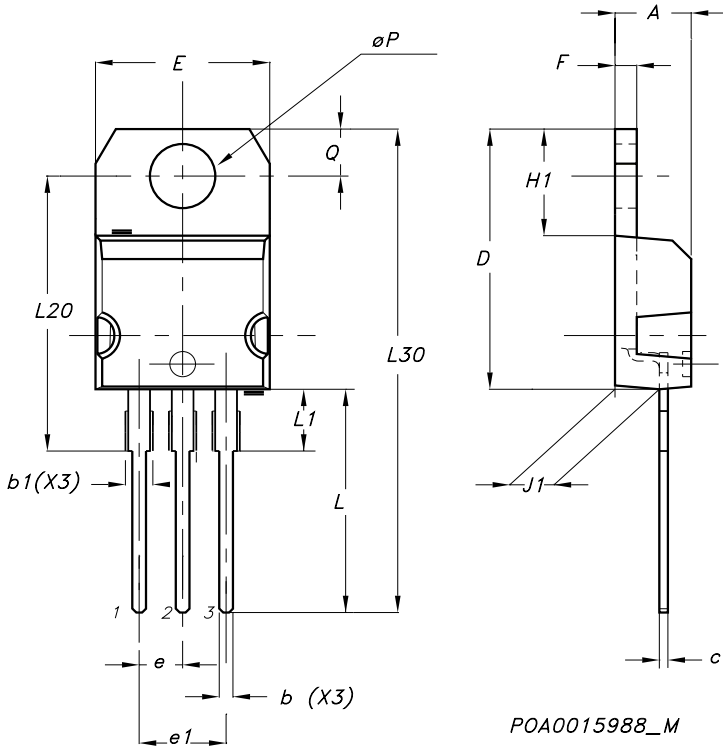
### Thermal Impedance for DPAK





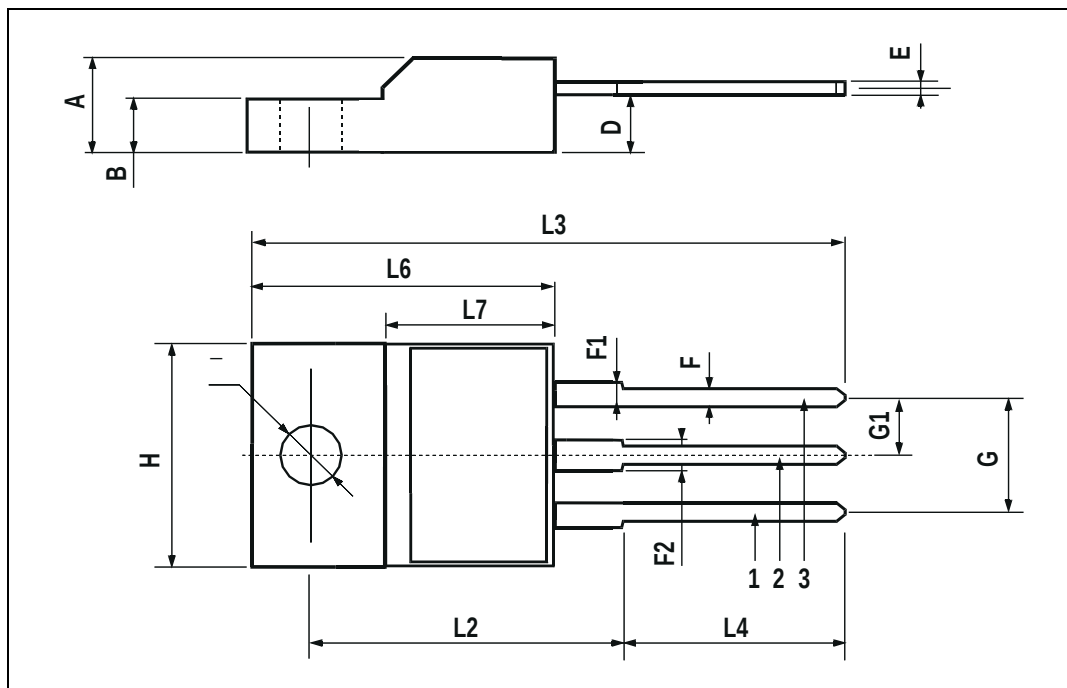
TO-220 MECHANICAL DATA

| DIM. | mm.   |       |       | inch  |       |       |
|------|-------|-------|-------|-------|-------|-------|
|      | MIN.  | TYP.  | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 4.40  |       | 4.60  | 0.173 |       | 0.181 |
| b    | 0.61  |       | 0.88  | 0.024 |       | 0.034 |
| b1   | 1.15  |       | 1.70  | 0.045 |       | 0.066 |
| c    | 0.49  |       | 0.70  | 0.019 |       | 0.027 |
| D    | 15.25 |       | 15.75 | 0.60  |       | 0.620 |
| E    | 10    |       | 10.40 | 0.393 |       | 0.409 |
| e    | 2.40  |       | 2.70  | 0.094 |       | 0.106 |
| e1   | 4.95  |       | 5.15  | 0.194 |       | 0.202 |
| F    | 1.23  |       | 1.32  | 0.048 |       | 0.052 |
| H1   | 6.20  |       | 6.60  | 0.244 |       | 0.256 |
| J1   | 2.40  |       | 2.72  | 0.094 |       | 0.107 |
| L    | 13    |       | 14    | 0.511 |       | 0.551 |
| L1   | 3.50  |       | 3.93  | 0.137 |       | 0.154 |
| L20  |       | 16.40 |       |       | 0.645 |       |
| L30  |       | 28.90 |       |       | 1.137 |       |
| øP   | 3.75  |       | 3.85  | 0.147 |       | 0.151 |
| Q    | 2.65  |       | 2.95  | 0.104 |       | 0.116 |



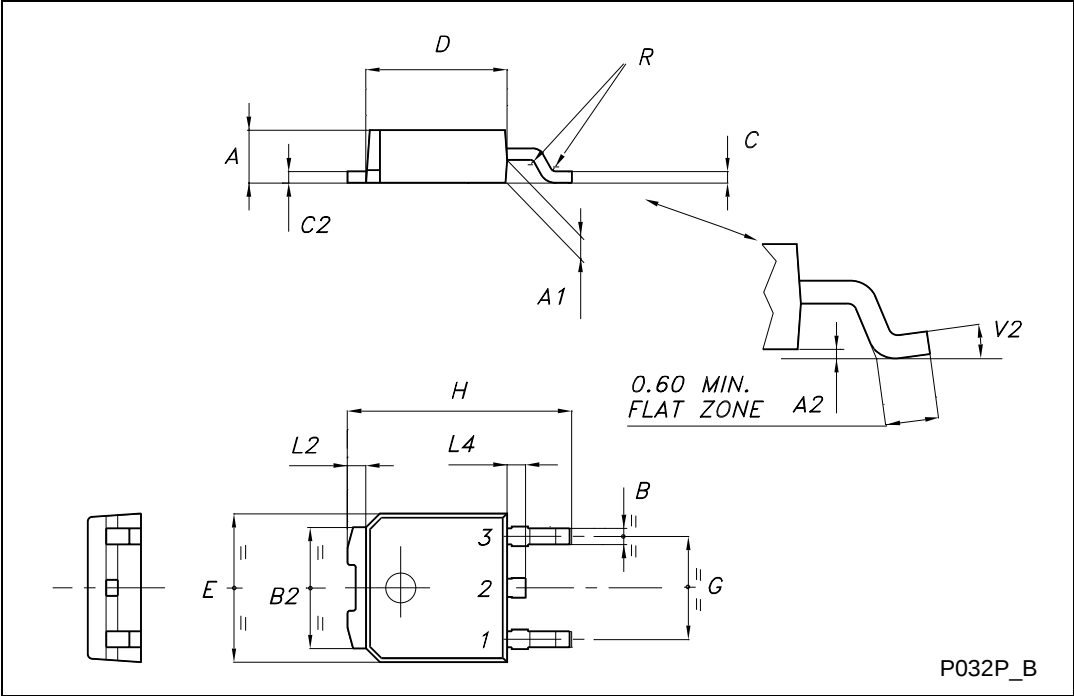
TO-220FP MECHANICAL DATA

| DIM. | mm   |      |      | inch  |       |       |
|------|------|------|------|-------|-------|-------|
|      | MIN. | TYP. | MAX. | MIN.  | TYP.  | MAX.  |
| A    | 4.4  |      | 4.6  | 0.173 |       | 0.181 |
| B    | 2.5  |      | 2.7  | 0.098 |       | 0.106 |
| D    | 2.5  |      | 2.75 | 0.098 |       | 0.108 |
| E    | 0.45 |      | 0.7  | 0.017 |       | 0.027 |
| F    | 0.75 |      | 1    | 0.030 |       | 0.039 |
| F1   | 1.15 |      | 1.7  | 0.045 |       | 0.067 |
| F2   | 1.15 |      | 1.7  | 0.045 |       | 0.067 |
| G    | 4.95 |      | 5.2  | 0.195 |       | 0.204 |
| G1   | 2.4  |      | 2.7  | 0.094 |       | 0.106 |
| H    | 10   |      | 10.4 | 0.393 |       | 0.409 |
| L2   |      | 16   |      |       | 0.630 |       |
| L3   | 28.6 |      | 30.6 | 1.126 |       | 1.204 |
| L4   | 9.8  |      | 10.6 | 0.385 |       | 0.417 |
| L6   | 15.9 |      | 16.4 | 0.626 |       | 0.645 |
| L7   | 9    |      | 9.3  | 0.354 |       | 0.366 |
| Ø    | 3    |      | 3.2  | 0.118 |       | 0.126 |



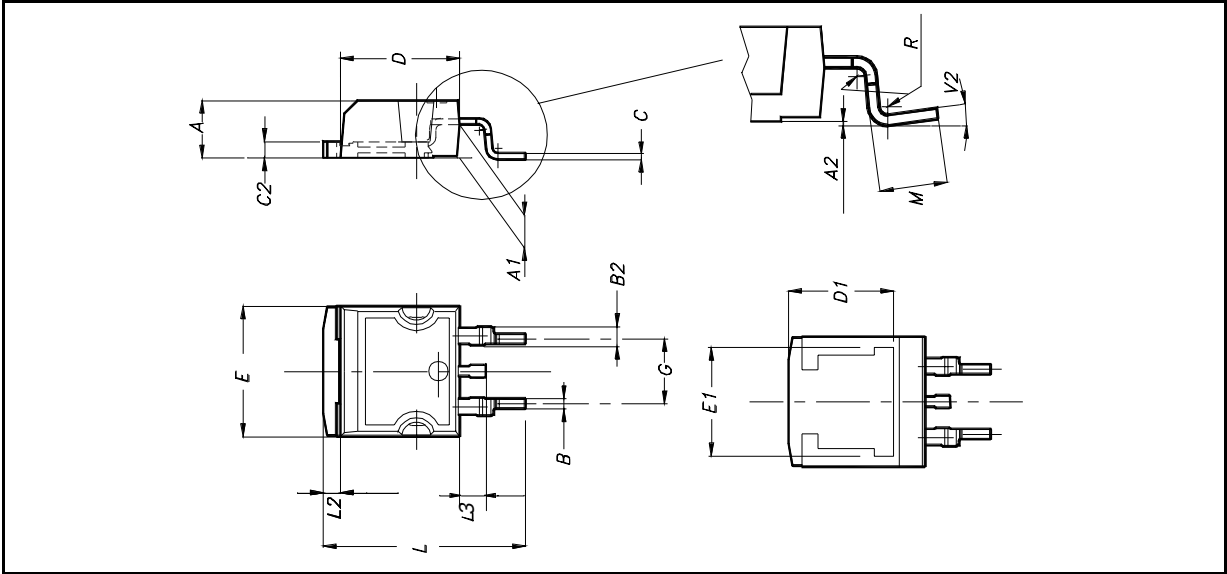
TO-252 (DPAK) MECHANICAL DATA

| DIM. | mm   |      |       | inch  |       |       |
|------|------|------|-------|-------|-------|-------|
|      | MIN. | TYP. | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 2.20 |      | 2.40  | 0.087 |       | 0.094 |
| A1   | 0.90 |      | 1.10  | 0.035 |       | 0.043 |
| A2   | 0.03 |      | 0.23  | 0.001 |       | 0.009 |
| B    | 0.64 |      | 0.90  | 0.025 |       | 0.035 |
| B2   | 5.20 |      | 5.40  | 0.204 |       | 0.213 |
| C    | 0.45 |      | 0.60  | 0.018 |       | 0.024 |
| C2   | 0.48 |      | 0.60  | 0.019 |       | 0.024 |
| D    | 6.00 |      | 6.20  | 0.236 |       | 0.244 |
| E    | 6.40 |      | 6.60  | 0.252 |       | 0.260 |
| G    | 4.40 |      | 4.60  | 0.173 |       | 0.181 |
| H    | 9.35 |      | 10.10 | 0.368 |       | 0.398 |
| L2   |      | 0.8  |       |       | 0.031 |       |
| L4   | 0.60 |      | 1.00  | 0.024 |       | 0.039 |
| V2   | 0°   |      | 8°    | 0°    |       | 0°    |

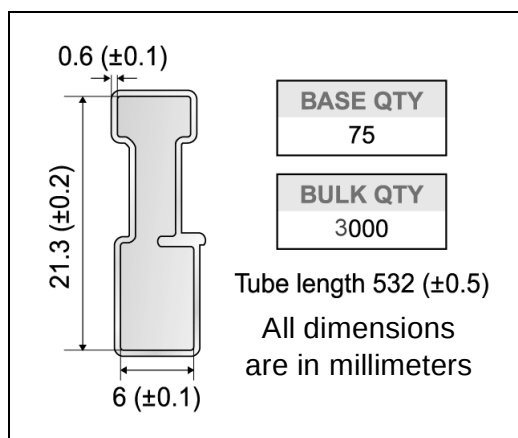
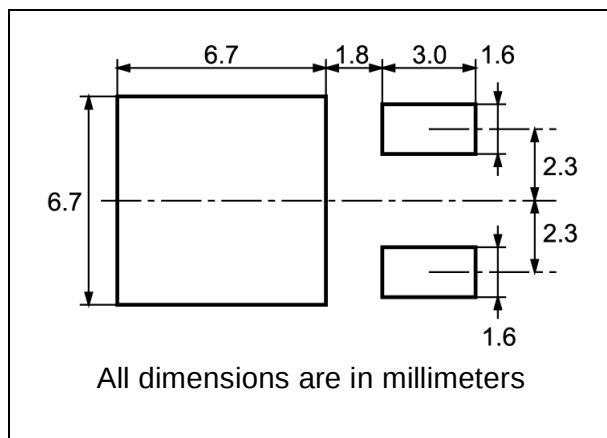


D<sup>2</sup>PAK MECHANICAL DATA

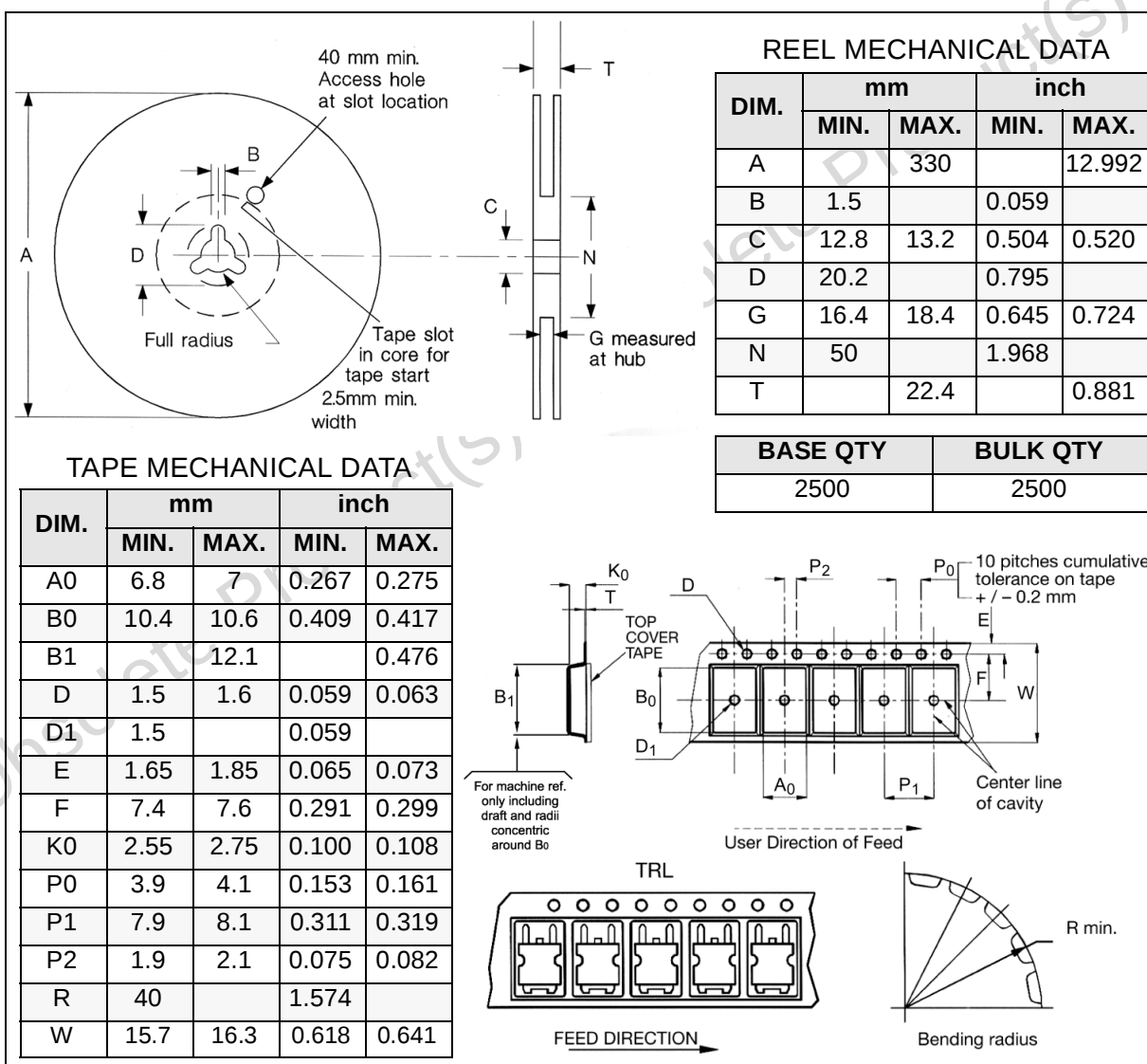
| DIM. | mm.  |     |       | inch  |       |       |
|------|------|-----|-------|-------|-------|-------|
|      | MIN. | TYP | MAX.  | MIN.  | TYP.  | MAX.  |
| A    | 4.4  |     | 4.6   | 0.173 |       | 0.181 |
| A1   | 2.49 |     | 2.69  | 0.098 |       | 0.106 |
| A2   | 0.03 |     | 0.23  | 0.001 |       | 0.009 |
| B    | 0.7  |     | 0.93  | 0.027 |       | 0.036 |
| B2   | 1.14 |     | 1.7   | 0.044 |       | 0.067 |
| C    | 0.45 |     | 0.6   | 0.017 |       | 0.023 |
| C2   | 1.23 |     | 1.36  | 0.048 |       | 0.053 |
| D    | 8.95 |     | 9.35  | 0.352 |       | 0.368 |
| D1   |      | 8   |       |       | 0.315 |       |
| E    | 10   |     | 10.4  | 0.393 |       |       |
| E1   |      | 8.5 |       |       | 0.334 |       |
| G    | 4.88 |     | 5.28  | 0.192 |       | 0.208 |
| L    | 15   |     | 15.85 | 0.590 |       | 0.625 |
| L2   | 1.27 |     | 1.4   | 0.050 |       | 0.055 |
| L3   | 1.4  |     | 1.75  | 0.055 |       | 0.068 |
| M    | 2.4  |     | 3.2   | 0.094 |       | 0.126 |
| R    |      | 0.4 |       |       | 0.015 |       |
| V2   | 0°   |     | 8°    |       |       |       |



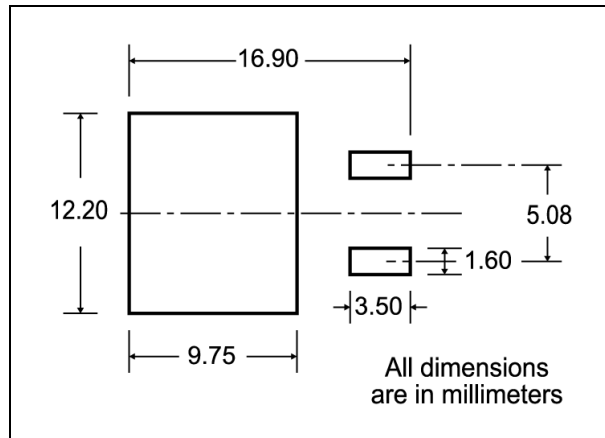
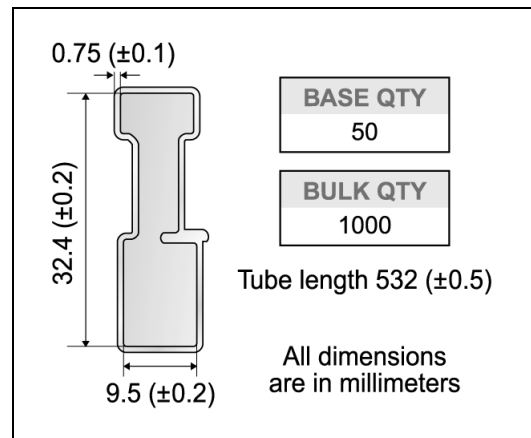
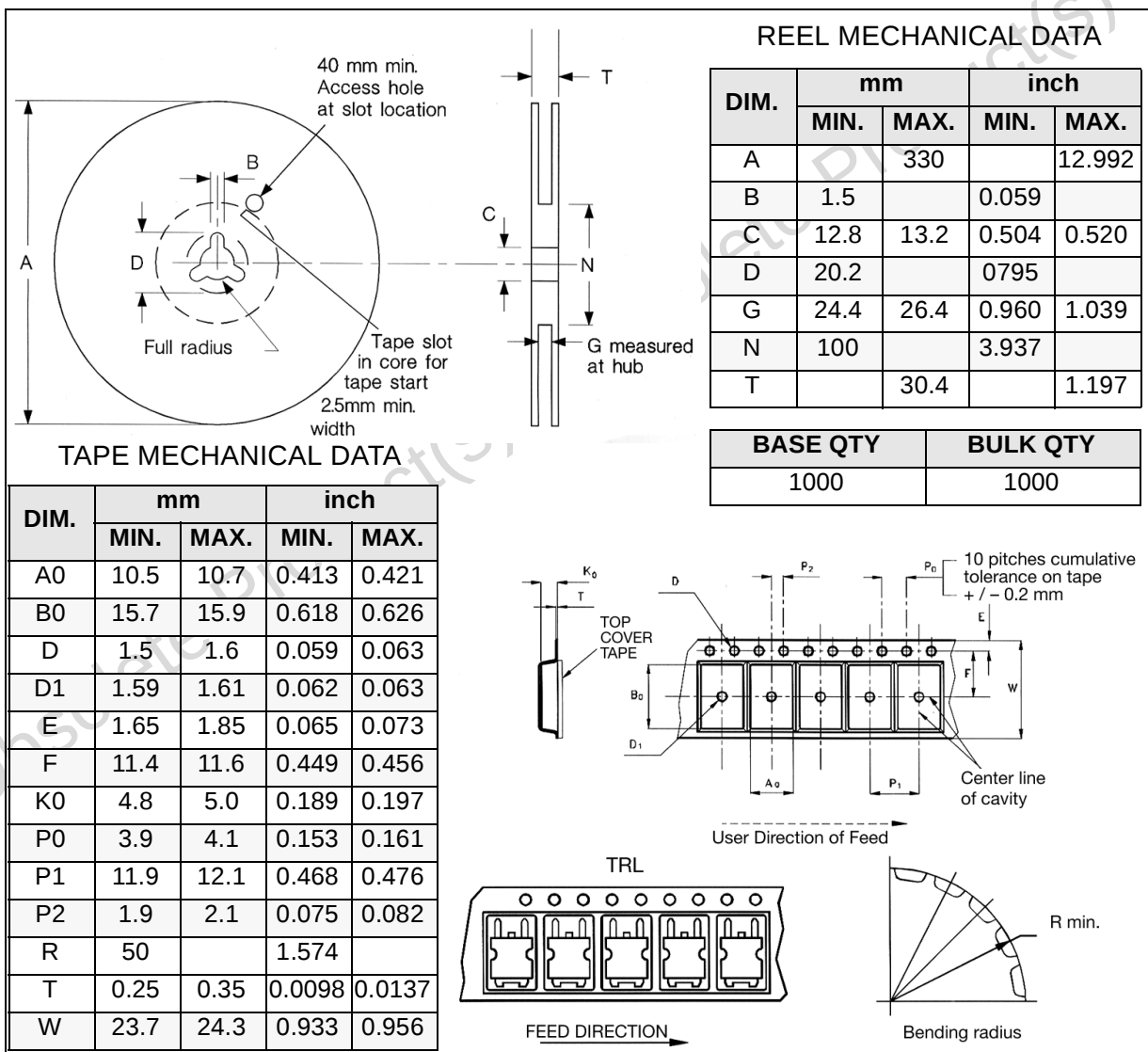
**TUBE SHIPMENT (no suffix)\***



### TAPE AND REEL SHIPMENT (suffix "T4")\*



\* on sales type

**D<sup>2</sup>PAK FOOTPRINT****TUBE SHIPMENT (no suffix)\*****TAPE AND REEL SHIPMENT (suffix "T4")\***

\* on sales

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